

**IR-Lumineszenzdiode (850 nm) mit hoher Ausgangsleistung**  
**High Power Infrared Emitter (850 nm)**  
**Lead (Pb) Free Product - RoHS Compliant**  
**SFH 4252**



**Vorläufige Daten / Preliminary Data**

**Wesentliche Merkmale**

- Infrarot LED mit sehr hoher Ausgangsleistung
- Emissionswellenlänge typ. 850 nm

**Anwendungen**

- Infrarotbeleuchtung für CMOS Kameras
- IR-Datenübertragung
- Sensorik

**Sicherheitshinweise**

Je nach Betriebsart emittieren diese Bauteile hochkonzentrierte, nicht sichtbare Infrarot-Strahlung, die gefährlich für das menschliche Auge sein kann. Produkte, die diese Bauteile enthalten, müssen gemäß den Sicherheitsrichtlinien der IEC-Normen 60825-1 und 62471 behandelt werden.

**Features**

- High Power Infrared LED
- Peak wavelength typ. 850 nm

**Applications**

- Infrared Illumination for CMOS cameras
- IR Data Transmission
- Optical sensors

**Safety Advises**

Depending on the mode of operation, these devices emit highly concentrated non visible infrared light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1 and IEC 62471.

| Typ<br>Type | Bestellnummer<br>Ordering Code | Strahlstärkegruppierung <sup>1)</sup> ( $I_F = 100 \text{ mA}$ , $t_p = 20 \text{ ms}$ )<br>Radiant Intensity Grouping <sup>1)</sup><br>$I_e \text{ (mW/sr)}$ |
|-------------|--------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------|
| SFH 4252    | Q65110A2468                    | >10 (typ. 16)                                                                                                                                                 |

<sup>1)</sup> gemessen bei einem Raumwinkel  $\Omega = 0.01 \text{ sr}$  / measured at a solid angle of  $\Omega = 0.01 \text{ sr}$



**ATTENTION - Observe Precautions For Handling - Electrostatic Sensitive Device**

**Grenzwerte** ( $T_A = 25\text{ °C}$ )**Maximum Ratings**

| Bezeichnung<br>Parameter                                                                                                                                                                                      | Symbol<br>Symbol  | Wert<br>Value  | Einheit<br>Unit |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------|----------------|-----------------|
| Betriebs- und Lagertemperatur<br>Operating and storage temperature range                                                                                                                                      | $T_{op}, T_{stg}$ | - 40 ... + 100 | °C              |
| Sperrspannung<br>Reverse voltage                                                                                                                                                                              | $V_R$             | 5              | V               |
| Vorwärtsgleichstrom<br>Forward current                                                                                                                                                                        | $I_F$             | 100            | mA              |
| Stoßstrom, $t_p = 10\text{ }\mu\text{s}$ , $D = 0$<br>Surge current                                                                                                                                           | $I_{FSM}$         | 1              | A               |
| Verlustleistung<br>Power dissipation                                                                                                                                                                          | $P_{tot}$         | 180            | mW              |
| Wärmewiderstand Sperrschicht - Umgebung bei<br>Montage auf FR4 Platine, Padgröße je 16 mm <sup>2</sup><br>Thermal resistance junction - ambient mounted<br>on PC-board (FR4), padsize 16 mm <sup>2</sup> each | $R_{thJA}$        | 450            | K/W             |
| Wärmewiderstand Sperrschicht - Lötstelle bei<br>Montage auf Metall-Block<br>Thermal resistance junction - soldering point,<br>mounted on metal block                                                          | $R_{thJS}$        | 200            | K/W             |

**Kennwerte** ( $T_A = 25\text{ °C}$ )**Characteristics**

| Bezeichnung<br>Parameter                                                                                      | Symbol<br>Symbol             | Wert<br>Value    | Einheit<br>Unit |
|---------------------------------------------------------------------------------------------------------------|------------------------------|------------------|-----------------|
| Wellenlänge der Strahlung<br>Wavelength at peak emission<br>$I_F = 100\text{ mA}$                             | $\lambda_{peak}$             | 850              | nm              |
| Spektrale Bandbreite bei 50% von $I_{max}$<br>Spectral bandwidth at 50% of $I_{max}$<br>$I_F = 100\text{ mA}$ | $\Delta\lambda$              | 35               | nm              |
| Abstrahlwinkel<br>Half angle                                                                                  | $\varphi$                    | $\pm 60$         | Grad<br>deg.    |
| Aktive Chipfläche<br>Active chip area                                                                         | $A$                          | 0.09             | mm <sup>2</sup> |
| Abmessungen der aktiven Chipfläche<br>Dimension of the active chip area                                       | $L \times B$<br>$L \times W$ | $0.3 \times 0.3$ | mm <sup>2</sup> |

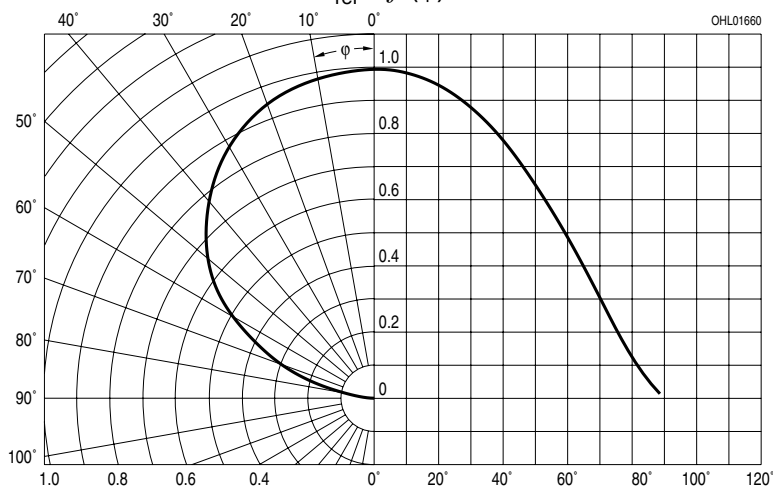
**Kennwerte** ( $T_A = 25\text{ °C}$ )**Characteristics** (cont'd)

| Bezeichnung<br>Parameter                                                                                                                                                                                                      | Symbol<br>Symbol      | Wert<br>Value                      | Einheit<br>Unit |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------|------------------------------------|-----------------|
| Schaltzeiten, $I_e$ von 10% auf 90% und von 90% auf 10%, bei $I_F = 100\text{ mA}$ , $R_L = 50\text{ }\Omega$<br>Switching times, $I_e$ from 10% to 90% and from 90% to 10%, $I_F = 100\text{ mA}$ , $R_L = 50\text{ }\Omega$ | $t_r, t_f$            | 12                                 | ns              |
| Durchlassspannung<br>Forward voltage<br>$I_F = 100\text{ mA}$ , $t_p = 20\text{ ms}$<br>$I_F = 1\text{ A}$ , $t_p = 100\text{ }\mu\text{s}$                                                                                   | $V_F$<br>$V_F$        | 1.5 (< 1.8)<br>2.4 (< 3.0)         | V<br>V          |
| Sperrstrom<br>Reverse current<br>$V_R = 5\text{ V}$                                                                                                                                                                           | $I_R$                 | not designed for reverse operation | $\mu\text{A}$   |
| Gesamtstrahlungsfluss<br>Total radiant flux<br>$I_F = 100\text{ mA}$ , $t_p = 20\text{ ms}$                                                                                                                                   | $\Phi_{e\text{ typ}}$ | 40                                 | mW              |
| Temperaturkoeffizient von $I_e$ bzw. $\Phi_e$ ,<br>$I_F = 100\text{ mA}$<br>Temperature coefficient of $I_e$ or $\Phi_e$ , $I_F = 100\text{ mA}$                                                                              | $TC_I$                | - 0.5                              | %/K             |
| Temperaturkoeffizient von $V_F$ , $I_F = 100\text{ mA}$<br>Temperature coefficient of $V_F$ , $I_F = 100\text{ mA}$                                                                                                           | $TC_V$                | - 0.7                              | mV/K            |
| Temperaturkoeffizient von $\lambda$ , $I_F = 100\text{ mA}$<br>Temperature coefficient of $\lambda$ , $I_F = 100\text{ mA}$                                                                                                   | $TC_\lambda$          | + 0.2                              | nm/K            |

**Strahlstärke  $I_e$  in Achsrichtung<sup>1)</sup>**gemessen bei einem Raumwinkel  $\Omega = 0.01$  sr**Radiant Intensity  $I_e$  in Axial Direction**at a solid angle of  $\Omega = 0.01$  sr

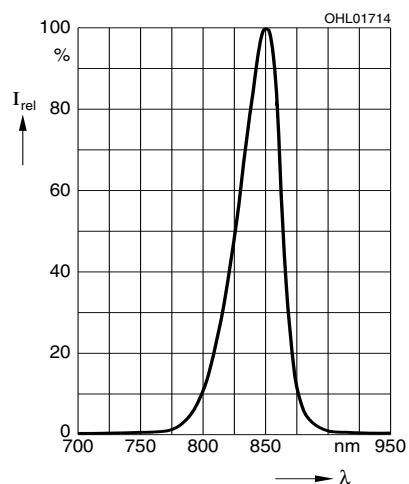
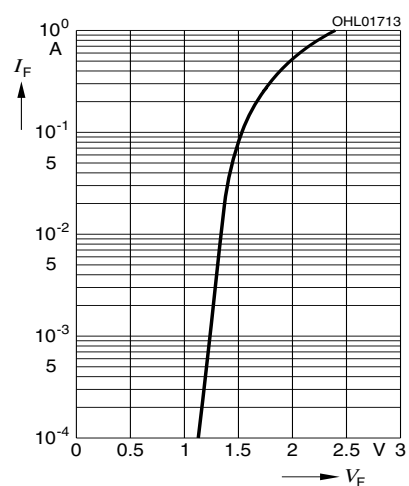
| Bezeichnung<br>Parameter                                              | Symbol                                     | Werte<br>Values |             | Einheit<br>Unit |
|-----------------------------------------------------------------------|--------------------------------------------|-----------------|-------------|-----------------|
|                                                                       |                                            | SFH 4252 -R     | SFH 4252 -S |                 |
| Strahlstärke<br>Radiant intensity<br>$I_F = 100$ mA, $t_p = 20$ ms    | $I_{e \text{ min}}$<br>$I_{e \text{ max}}$ | 10<br>20        | 16<br>32    | mW/sr<br>mW/sr  |
| Strahlstärke<br>Radiant intensity<br>$I_F = 1$ A, $t_p = 100$ $\mu$ s | $I_{e \text{ typ}}$                        | 100             | 140         | mW/sr           |

<sup>1)</sup> Nur eine Gruppe in einer Verpackungseinheit (Streuung kleiner 2:1) /  
Only one group in one packing unit (variation lower 2:1)

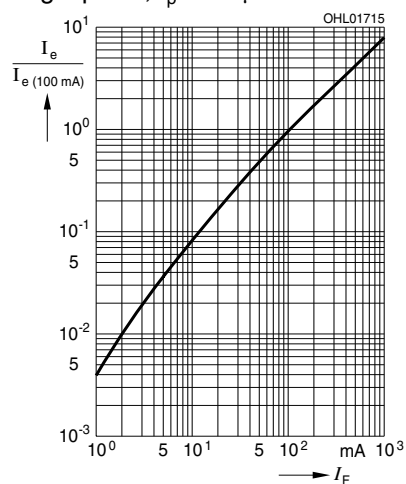
**Abstrahlcharakteristik****Radiation Characteristics  $I_{\text{rel}} = f(\varphi)$** 

**Relative Spectral Emission**

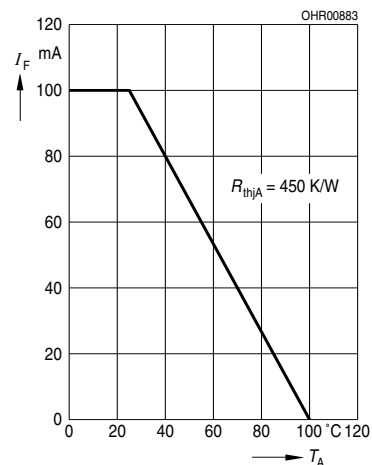
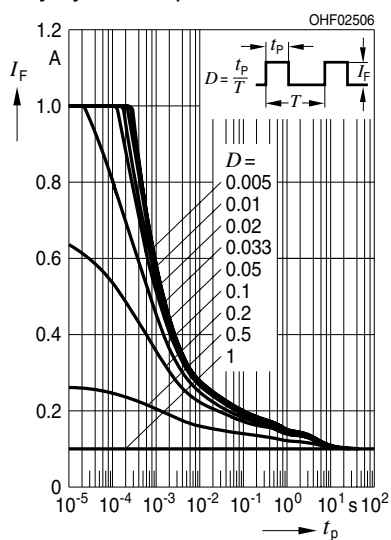
$$I_{\text{rel}} = f(\lambda)$$

**Forward Current  $I_F = f(V_F)$** Single pulse,  $t_p = 20 \mu\text{s}$ 

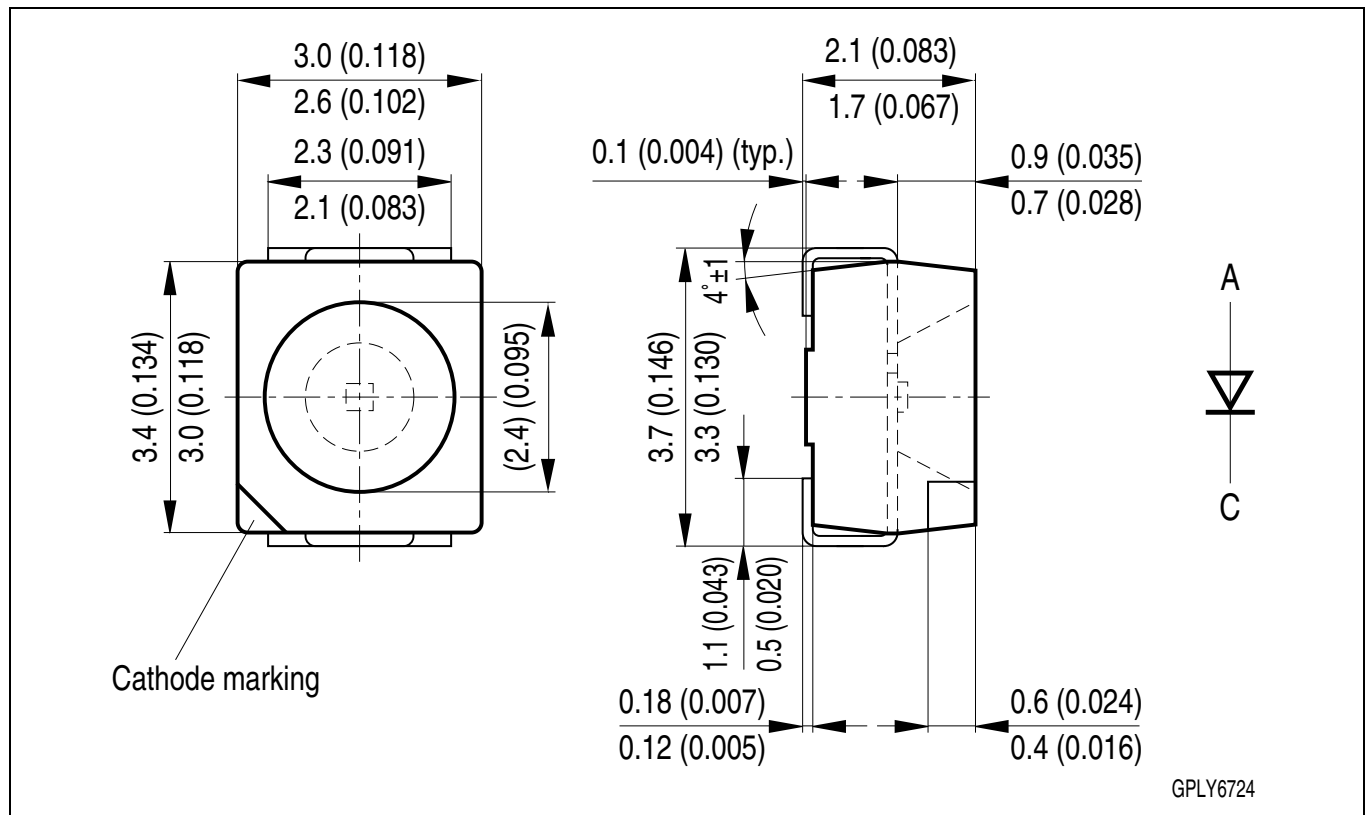
$$\text{Radiant Intensity } \frac{I_e}{I_e 100 \text{ mA}} = f(I_F)$$

Single pulse,  $t_p = 20 \mu\text{s}$ **Max. Permissible Forward Current**

$$I_F = f(T_A), R_{\text{thJA}} = 450 \text{ K/W}$$

**Permissible Pulse Handling**
 $I_F = f(\tau)$ ,  $T_A = 25^\circ\text{C}$ ,  
duty cycle  $D = \text{parameter}$ 


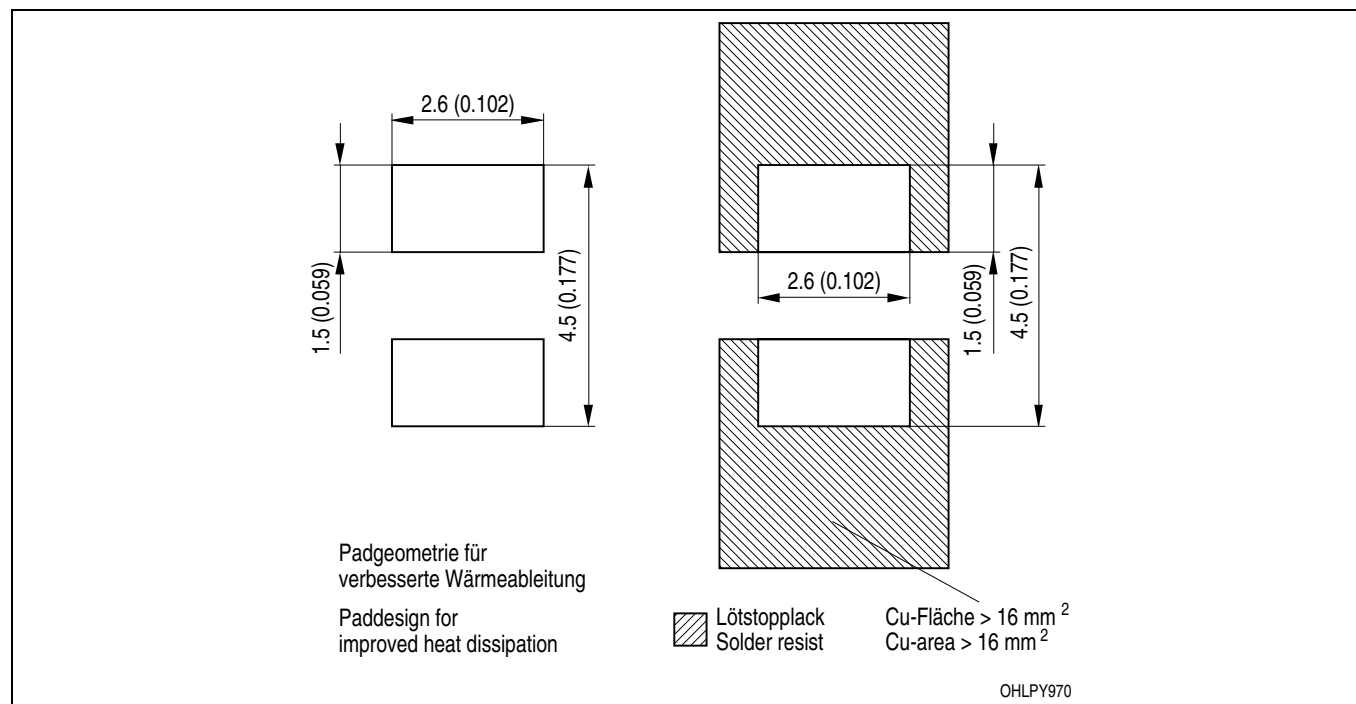
# **Maßzeichnung** **Package Outlines**



Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

|                                        |                                                |
|----------------------------------------|------------------------------------------------|
| Gehäuse / Package                      | TOPLED®, klarer Verguss / TOPLED®, clear resin |
| Anschlussbelegung<br>Pin configuration | siehe Zeichnung<br>see drawing                 |

## Empfohlenes Lötpaddesign Recommended Solder Pad Design



Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

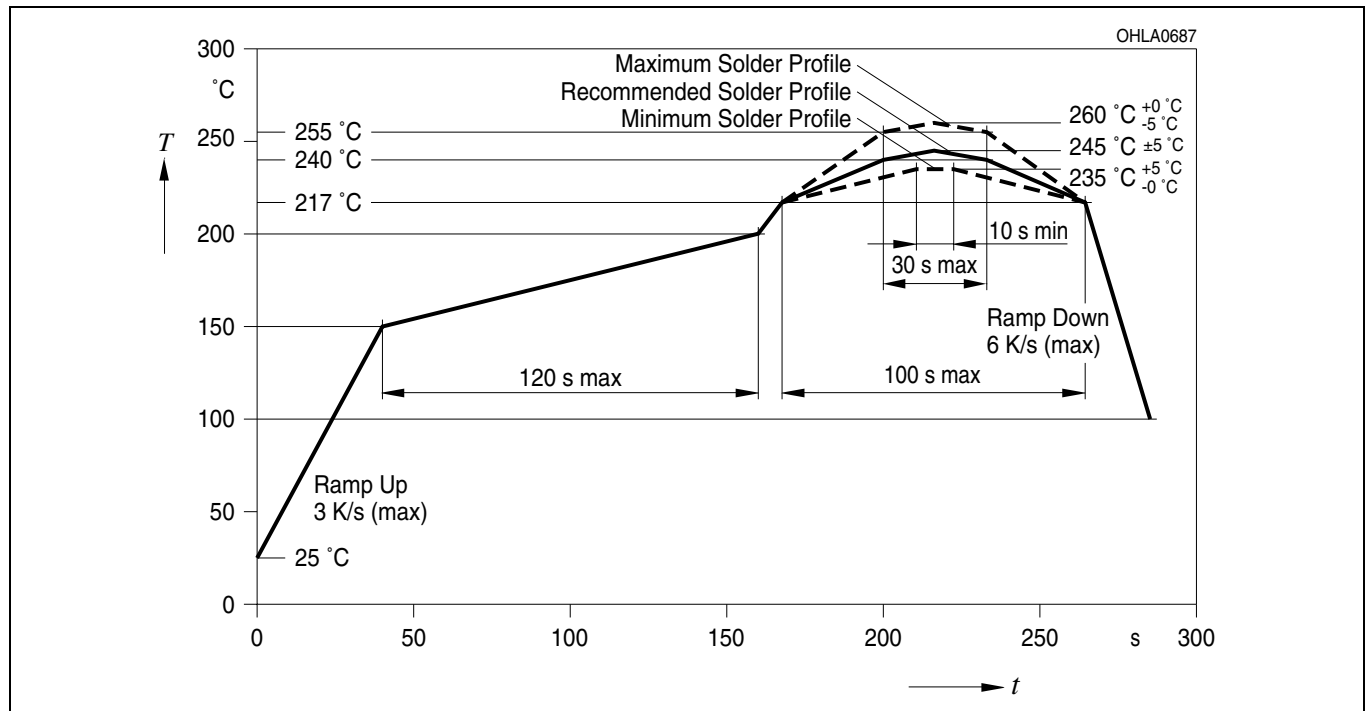
**Lötbedingungen****Soldering Conditions****IR-Reflow Lötprofil für bleifreies Löt****IR Reflow Soldering Profile for lead free soldering**

Vorbehandlung nach JEDEC Level 2

Preconditioning acc. to JEDEC Level 2

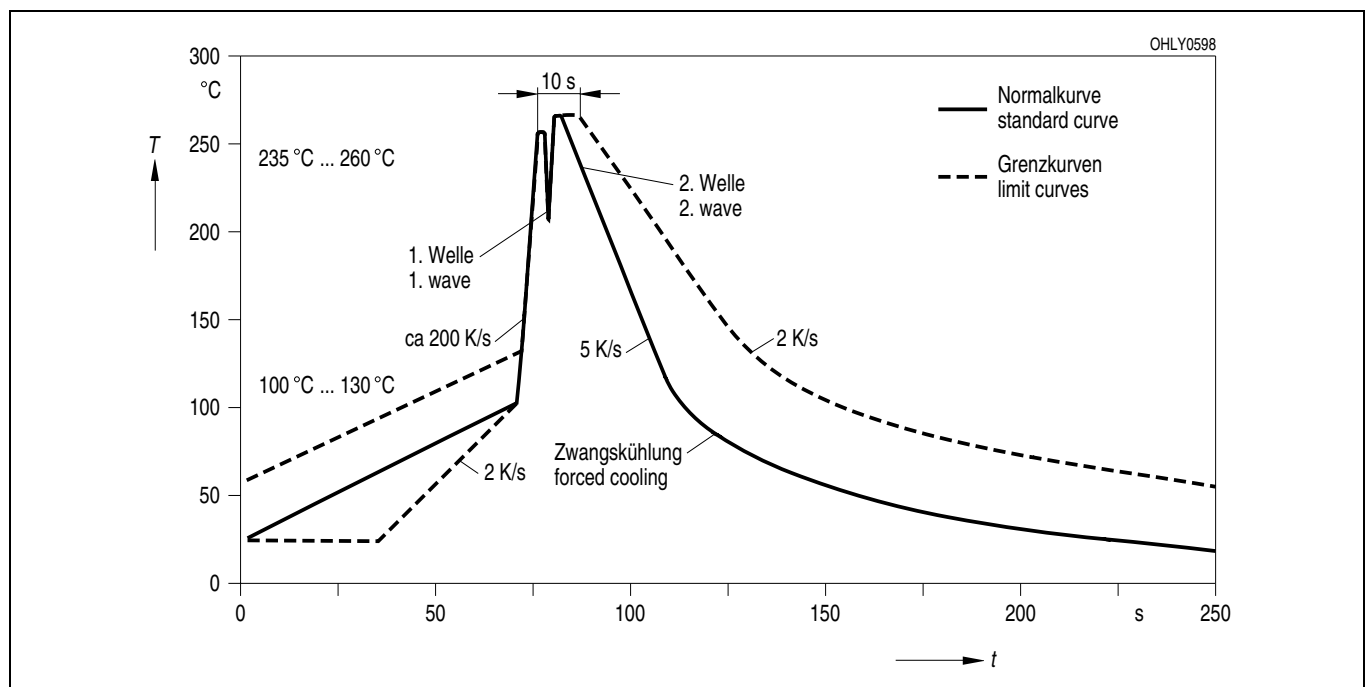
(nach J-STD-020B)

(acc. to J-STD-020B)

**Wellenlötten (TTW)****TTW Soldering**

(nach CECC 00802)

(acc. to CECC 00802)



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#### **Packing**

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

**Components used in life-support devices or systems must be expressly authorized for such purpose!** Critical components <sup>1</sup>, may only be used in life-support devices or systems <sup>2</sup> with the express written approval of OSRAM OS.

<sup>1</sup> A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or effectiveness of that device or system.

<sup>2</sup> Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health of the user may be endangered.